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Partial Oxidation of Methane with Nitrous Oxide in a Dielectric-Barrier Discharge System

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The partial oxidation of $\mathrm{CH_4}$ by $\mathrm{N_2O}$ was investigated in a dielectric-barrier discharge system at atmospheric pressure. $\mathrm{CH_4}$ converted to $\mathrm{CH_3OH}$, HCHO, and CO in this system. Total yield of $\mathrm{CH_3OH}$ and HCHO reached about 10 % in the Ar stream. It was suggested that excited Ar species and electrons might behave important role to promote the partial oxidation reaction.

CH₃OH is an important material from the point of view as a gasoline additive and as an automobile fuel. CH₃OH is also key material to produce hydrogen that will be used with fuel cells. In general, CH₃OH is manufactured from synthesis gas over Cu-based catalysts.¹ The partial oxidation of CH₄ to CH₃OH is more desirable if high selectivity to CH₃OH and reasonable conversion rate can be obtained. Active research efforts are directed to find out processes that can selectively oxidize CH₄ to CH₃OH.²⁻⁴ It's widely recognized that nonequilibrium plasma technique is one of the solutions for this process.⁵⁻⁷ In this report, partial oxidation of CH₄ has been investigated by using dielectric-barrier discharge (DBD) system. CH₄ could directly be converted to CH₃OH by N₂O as an oxidant, and high yield for CH₃OH was achieved with the system.

The DBD plasma reactor in this work was basically similar to that of Chen et al.8 A Cu rod was used as internal electrode (8 mm od, 100 mm length) that was supported in the center of quartz tube (10 mm id, 200 mm length). thickness of quartz barrier was 1 mm. Outer surface of the glass tube was tightly covered by Cu foil as external electrode (7 cm length). High-voltage power was supplied between two electrodes (gap = 1mm) with an amplifier and a function generator. The electric conditions such as wave shape, frequency, voltage, and current were simultaneously monitored with a digital oscilloscope. In this study, sin wave ac (frequency, f = 1 kHz) was supplied to produce a DBD plasma. The reactant gases were mixed and supplied with mass flow controllers. In most cases the reactant gas mixture consisted of 10% CH₄ and 10% N₂O in Ar was supplied at a flow rate (F_R) of 50 cm³(STP)•min⁻¹. The reactant and product were analyzed by GC with Porapak Q and Molecular Sieve 5A columns. Plasma diagnoses were performed with an emission spectrometer.

The intensity of the emission spectra due to Ar excitations proportionally increased with increasing supplied voltage. ^{8,9} When reactant gas was introduced into Ar stream, new emission peaks due to the exited species of reactant were observed, and at the same time the emission intensities from Ar significantly decreased. Figure 1 shows the effect of input voltage on the yields of CH₃OH and HCHO. The other products were CO, C₂H₆, H₂, N₂, and H₂O. It is clearly demonstrated that the reaction starts at 1 kV, then the yield of CH₃OH and HCHO increases with the increase of input voltage. The overall yield of CH₃OH and HCHO exceeded 10% at an input voltage of 7 kV. This value is clearly higher than those of conventional catalysis,

i. e., 3.4% with CH₄/N₂O on Mo/Carb-O-Sil at 870 K, 2 7% with CH₄/NO on V₂O₅/SiO₂ at 883 K, 3 and 1.4% with CH₄/O₂ on CoO-MgO-Al₂O₃ at 730 K. 4

Figure 2 shows the effect of residence time (t_R) on the selectivity of major products, such as CH₃OH, HCHO, and CO. The selectivity of CH₃OH gradually decreased with the increase of the residence time. The selectivity of HCHO increased with increasing the residence time, then decreased at a longer residence time above 0.022 s. However, the selectivity of CO monotonously increased with increasing the time. It was speculated that the initially formed CH₃OH was oxidized to HCHO, which finally converted to CO.¹⁰ The selectivity to CH₃OH increased with the decrease of input voltage. From these points of view, it's concluded that CH₃OH is easily decomposed to HCHO and CO.¹¹ It is suggested for the improvement of CH₃OH selectivity, therefore, to be removed CH₃OH formed from the plasma zone as soon as possible.

Table 1 shows the energy efficiency (η_e) in the CH₃OH and HCHO formation.¹² Roughly speaking, the energy efficiency decreased with increasing the input voltage. The estimated energy efficiency of HCHO was higher than that of CH₃OH in whole range of the supplied voltage. From this result, we could estimate the specific power consumption¹³ that was 468 ~ 540 MJ/kg-(CH₃OH + HCHO) at 3 ~ 7 kV of supplied voltage. This value was significantly smaller than that obtained by Suib et al.⁷ in a microwave-induced plasma reactor (2106 MJ/kg-CH₃OH).

Figures 3A and 3B show the rates of formation of CH₃OH, HCHO, and CO in the presence and the absence of Ar, respectively. It should be noted that the minimum voltage to perform the reaction strongly reduced by the presence of Ar. It is considered, therefore, that excited Ar gives the charge and energy to the reactant molecules by collisions.⁹ Hiraoka et al.¹⁴

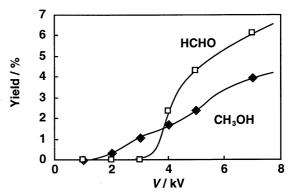


Figure 1. Effect of applied voltage (V) on the yield for CH₃OH and HCHO. Electrical conditions: f = 1 kHz ac (sin wave). Reaction conditions: CH₄ = 10%, N₂O = 10%, balance gas = Ar, $F_R = 50$ cm³(STP)•min⁻¹.

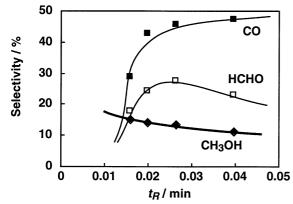


Figure 2. Effect of residence time (t_R) on the selectivity of products on partial oxidation of CH₄ with N₂O. Electrical conditions: V = 4 kV, f = 1 kHz ac (sin wave). Reaction conditions: CH₄ = 10%, N₂O = 10%, balance gas = Ar, $F_R = 50 \text{ cm}^3(\text{STP})\text{-min}^{-1}$.

Table 1. Electrical conditions and the energy efficiency (η_e) on partial oxidation of methane in DBD plasma

V/kV	Power / W	η_e / mol·(kWh) ⁻¹	
		CH₃OH	НСНО
2.0	0.33	0.070	-
3.0	1.73	0.097	0.168
4.0	3.06	0.092	0.176
5.0	5.77	0.063	0.147
6.0	8.48	0.047	0.131
7.0	9.98	0.040	0.115

Electrical conditions: ac sin wave, f = 1 kHz, Cu electrode, gap = 1 mm. Reaction conditions: CH₄ = 10%, N₂O = 10%, balance gas = Ar, $F_R = 50$ cm³(STP)•min⁻¹.

reported that CH₄ plasma in glow discharge system had two kinds of reaction mechanisms such as radical and ionic processes. No appreciable emission peaks due to any ionic species were observed in the present reaction condition examined. It is supposed, therefore, that the partial oxidation of CH₄ with N₂O in DBD system is performed via radical reaction process. On the other hand, the reaction rate of HCHO formation in the absence of Ar (Figure 3B) was higher than that in the presence of Ar (Figure 3A). From this result, electrons behave important role at the high voltage condition, i. e., the reactant may directly be excited by electrons at an initial step of the reaction.¹⁰ In the presence of Ar, electrons are probably spent to excite Ar. Eliasson et al.6 has pointed out that the excited oxygen atoms O(1D) act an important role in providing initial free radicals on the CH₄ and air plasma system. It's well known that the bonding energy between nitrogen atom and oxygen atom in N₂O is weak enough (167 kJ•mol⁻¹) to supply excited oxygen species in this system. This may be reason why the present results show small specific power consumption. It is concluded, therefore, that the excited Ar may give the charge and energy to CH₄ to produce the activated species, such as CH₃, CH₂, CH radicals, react with the excited oxygen or OH

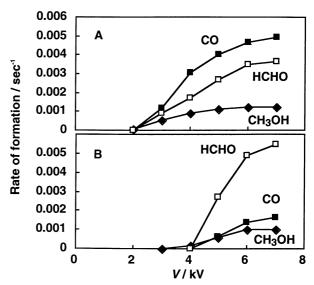


Figure 3. Effect of applied voltage (*V*) on the formation rate of products: **A**, Ar = 80%, CH₄ = 10%, N₂O = 10%; **B**, CH₄ = 50%, N₂O = 50%; F_R = 50 cm³(STP)•min⁻¹. Electrical conditions: f = 1 kHz ac (sin wave).

radicals.^{6,15} Further detailed investigations are, of course, required to gain in sight into the mechanism in this plasma reaction.

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